

# GBPC35005/W - GBPC3510/W

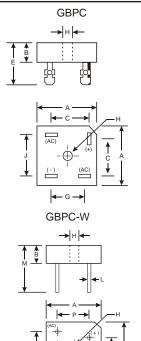
## 35A GLASS PASSIVATED BRIDGE RECTIFIER

#### Features

- Glass Passivated Die Construction
- Low Reverse Leakage Current
- Low Power Loss, High Efficiency
- Surge Overload Rating to 400A Peak
- Metal Base for Maximum Heat Dissipation
- Case to Terminal Isolation Voltage 1500V
- UL Listed Under Recognized Component Index, File Number E94661
- Lead Free Finish, RoHS Compliant (Note 4)

## Mechanical Data

- Case: GBPC / GBPC-W
- Case Material: Molded Plastic with Heatsink Internally Mounted in the Bridge Encapsulation. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Finish ¾ Silver. Plated Leads Solderable per MIL-STD-202, Method 208 ④
- Polarity: As Marked on Case
- Mounting: Through Hole for #10 Screw
- Mounting Torque: 8.0 Inch-pounds Maximum
- Ordering Information: See Last Page
- Marking: Type Number
- GBPC Weight: 20 grams (approximate)
- GBPC-W Weight: 14 grams (approximate)



GBPC / GBPC-W					
Dim	Min Max				
A	28.30	28.80			
В	7.40	8.25			
С	16.10	17.10			
E	18.80 21.30				
G	13.80	14.80			
Н	Hole for #10 screw				
	5.08Æ	5.59Æ			
J	17.60	18.60			
К	10.90 11.90				
L	0.97Æ	1.07Æ			
М	31.80	3⁄4			
Р	17.60	18.60			
All Dimensions in mm					

"W" Suffix Designates Wire Leads No Suffix Designates Faston Terminals

@ T<sub>A</sub> = 25°C unless otherwise specified

## Maximum Ratings and Electrical Characteristics

Single phase, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

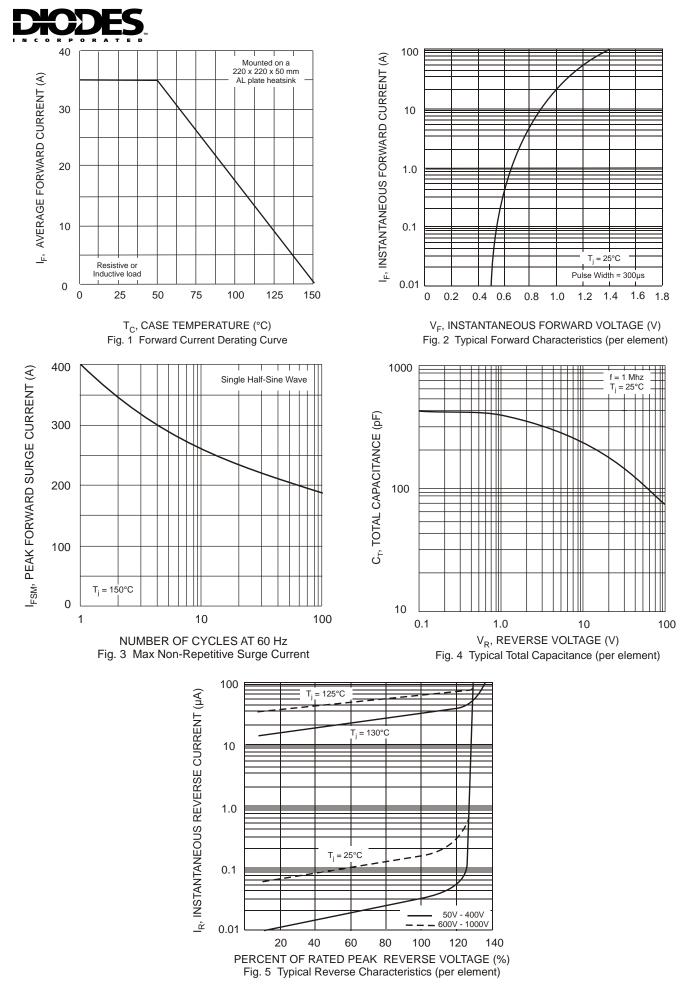
Characteristic		Symbol	GBPC35 005/W	GBPC35 01/W	GBPC35 02/W	GBPC35 04/W	GBPC35 06/W	GBPC35 08/W	GBPC35 10/W	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage		V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	50	100	200	400	600	800	1000	V
RMS Reverse Voltage		V <sub>R(RMS)</sub>	35	70	140	280	420	560	700	V
Average Rectified Output Current	@ T <sub>C</sub> = 50°C	lo				35				А
Non-Repetitive Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rated load		IFSM	400						А	
Forward Voltage (per element) $@ I_F = 17.5A$		V <sub>FM</sub>	1.1						V	
Peak Reverse Current at Rated DC Blocking Voltage	@ T <sub>C</sub> = 25°C @ T <sub>C</sub> = 125°C	I <sub>R</sub>				5.0 500				mA
I <sup>2</sup> t Rating for Fusing	(Note 1)	l <sup>2</sup> t				660				A <sup>2</sup> s
Typical Total Capacitance	(Note 2)	CT				300				pF
Typical Thermal Resistance per leg	(Note 3)	R <sub>qJC</sub>				1.2				°C/W
Operating and Storage Temperature Range		T <sub>j,</sub> T <sub>STG</sub>	-65 to +150						°C	

Notes: 1. Non-repetitive, for t > 1.0ms and t < 8.3ms.

2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

3. Thermal resistance junction to case mounted on heatsink.

4. RoHS revision 13.2.2003. Glass and High Temperature Solder Exemptions Applied, see EU Directive Annex Notes 5 and 7.





### Ordering Information (Note 5)

Device	Packaging	Shipping		
GBPC35005	GBPC	100/Tray		
GBPC3501	GBPC	100/Tray		
GBPC3502	GBPC	100/Tray		
GBPC3504	GBPC	100/Tray		
GBPC3506	GBPC	100/Tray		
GBPC3508	GBPC	100/Tray		
GBPC3510	GBPC	100/Tray		
GBPC35005W	GBPC-W	100/Tray		
GBPC3501W	GBPC-W	100/Tray		
GBPC3502W	GBPC-W	100/Tray		
GBPC3504W	GBPC-W	100/Tray		
GBPC3506W	GBPC-W	100/Tray		
GBPC3508W	GBPC-W	100/Tray		
GBPC3510W	GBPC-W	100/Tray		

Notes: 5. For packaging details, visit our website at http://www.diodes.com/datasheets/ap2008.pdf.

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